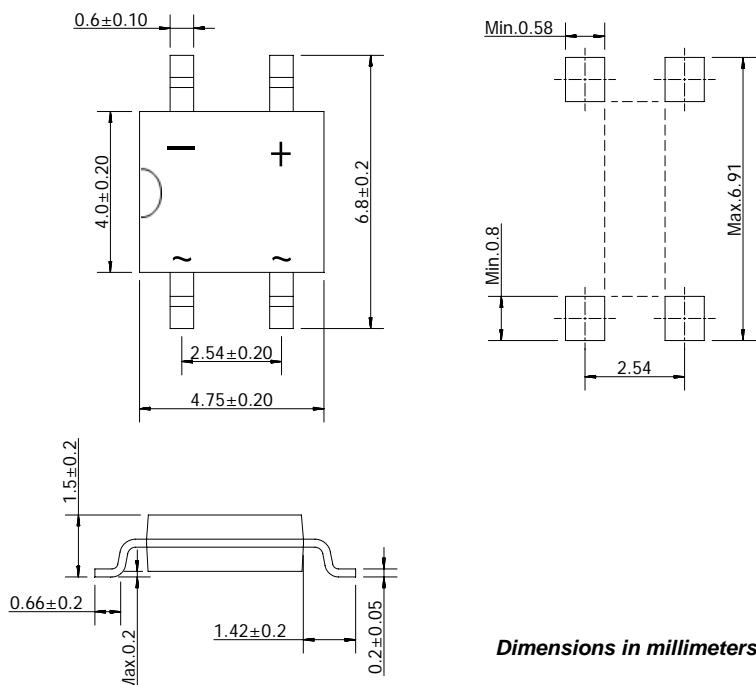


GLASS PASSIVATED SINGLE-PHASE BRIDGE RECTIFIER

Reverse Voltage 200to1000 Volts Forward Current 0.8 Amperes

Features

- ◆ Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- ◆ High surge current capability
- ◆ Ideal for printed circuit boards
- ◆ Glass passivated chip junction

Case Style: MBF**Mechanical Data****Case:** Molded plastic body over passivated junctions**Terminals:** Plated leads solderable per MIL-STD-750,

Method 2026

High temperature soldering guaranteed:

260°C/20 seconds

Mounting Position: Any**Weight:** 0.07oz., 0.2g**Absolute Maximum Ratings TL=25°C unless otherwise specified.**

Parameter	Symbol	MB2F	MB4F	MB6F	MB8F	MB10F	Unit
Maximum repetitive peak reverse voltage	V _{RRM}	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	200	400	600	800	1000	V
Maximum average forward output current rectified (see Fig.1)	I _{F(AV)}			0.5 ⁽¹⁾			A
on glass-epoxy P.C.B. on aluminum substrate				0.8 ⁽²⁾			
Peak forward surge current single sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}			30			A
Rating for fusig (t<8.3ms)	I ² t			3.7			A ² sec
Typical junction capacitance per leg at 4.0V 1.0Mhz	C _J			13			pF
Operating junction temperature range	T _J			-55 to +150			°C
Storage temperature range	T _{STG}			-55 to +150			°C

Electrical Characteristics TL=25°C unless otherwise specified.

Maximum instantaneous forward voltage drop per leg at 0.4A	V _F	1.00	V
Maximum DC reverse current at rated DC blocking voltage per leg	I _R	5 100	µA
Typical thermal resistance per leg	R _{θJA} R _{θJA} R _{θJL}	70 ⁽²⁾ 85 ⁽¹⁾ 20 ⁽¹⁾	°C/W

Notes:

(1) On glass epoxy P.C.B mounted on 0.05"×0.05"(1.3×1.3mm) pads

(2) On aluminum substrate P.C.B. with an area of 0.8"×0.8" (20×20mm) mounted on 0.05"×0.05"(1.3×1.3mm)solder pad

■ Ratings and Characteristic Curves (TA= 25°C unless otherwise noted)

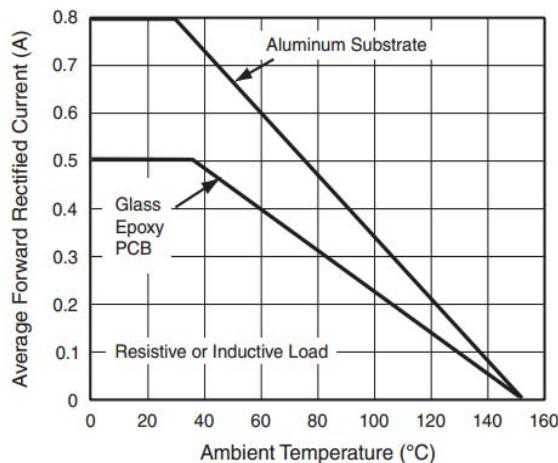


Fig. 1 - Derating Curve for Output Rectified Current

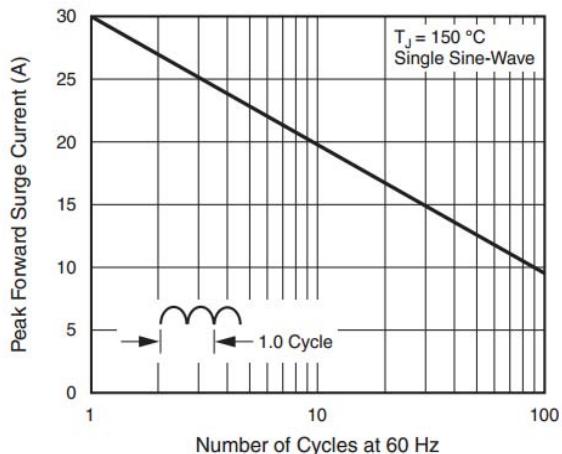


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

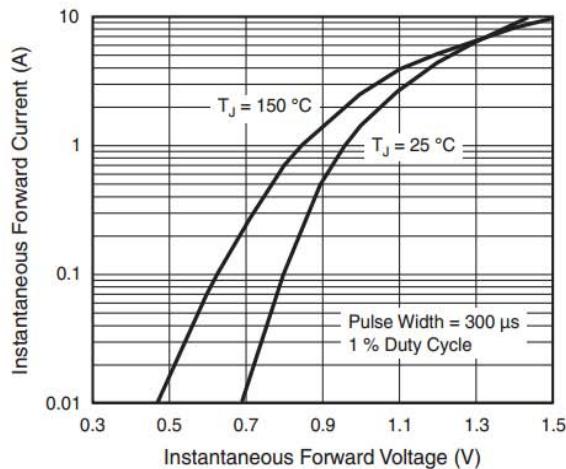


Fig. 3 - Typical Forward Voltage Characteristics Per Diode

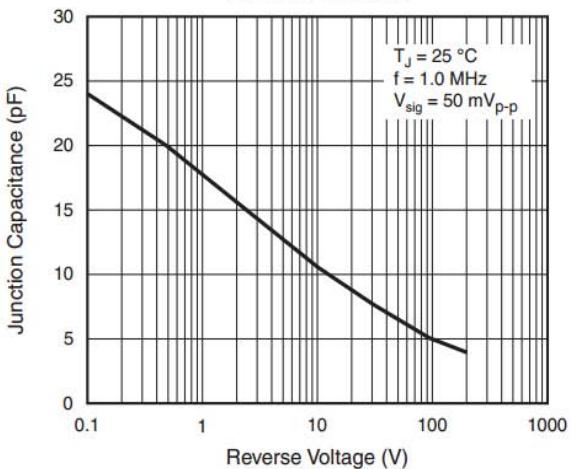


Fig. 5 - Typical Junction Capacitance Per Diode

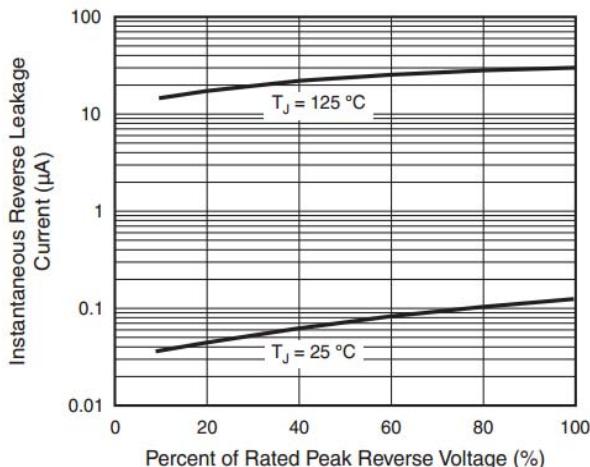


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode